Elerical Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
Off Characteristics						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I_D = -250 μA	-60	--	--	V
ΔBV_{DSS} /ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = -250 μA, Referenced to 25°C	--	-0.06	--	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = -60 V, V_{GS} = 0 V	--	--	-1	μA
		V_{DS} = -48 V, T_C = 150°C	--	--	-10	μA
I_{GSSF}	Gate-Body Leakage Current, Forward	V_{GS} = -25 V, V_{DS} = 0 V	--	--	-100	nA
I_{GSSR}	Gate-Body Leakage Current, Reverse	V_{GS} = 25 V, V_{DS} = 0 V	--	--	100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS} = V_{GS}, I_D = -250 μA	-2.0	--	-4.0	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	V_{GS} = -10 V, I_D = -23.5 A	--	0.021	0.026	Ω
g_{FS}	Forward Transconductance	V_{DS} = -30 V, I_D = -23.5 A (Note 4)	--	21	--	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = -25 V, V_{GS} = 0 V, f = 1.0 MHz	--	2800	3600	pF
C_{oss}	Output Capacitance		--	1300	1700	pF
C_{rss}	Reverse Transfer Capacitance		--	320	420	pF
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = -30 V, I_D = -23.5 A, R_G = 25 Ω (Note 4, 5)	--	50	110	ns
t_r	Turn-On Rise Time		--	450	910	ns
$t_{d(off)}$	Turn-Off Delay Time		--	100	210	ns
t_f	Turn-Off Fall Time		--	195	400	ns
Q_g	Total Gate Charge	V_{DS} = -48 V, I_D = -47 A, V_{GS} = -10 V (Note 4, 5)	--	84	110	nC
Q_{gs}	Gate-Source Charge		--	18	--	nC
Q_{gd}	Gate-Drain Charge		--	44	--	nC
Drain-Source Diode Characteristics and Maximum Ratings						
I_S	Maximum Continuous Drain-Source Diode Forward Current		--	--	-47	A
I_{SM}	Maximum Pulsed Drain-Source Diode Forward Current		--	--	-188	A
V_{SD}	Drain-Source Diode Forward Voltage	V_{GS} = 0 V, I_S = -47 A	--	--	-4.0	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, I_S = -47 A, dI_F / dt = 100 A/μs (Note 4)	--	130	--	ns
Q_{rr}	Reverse Recovery Charge		--	0.55	--	μC

Notes:
1. Repetitive Rating : Pulse width limited by maximum junction temperature
2. L = 0.43mH, I_{AS} = -47A, V_{DD} = -25V, R_G = 25 Ω, Starting T_J = 25°C
3. I_{SD} ≤ -47A, di/dt ≤ 300A/μs, V_{DD} ≤ BV_{DSS}, Starting T_J = 25°C
4. Pulse Test : Pulse width ≤300μs, Duty cycle ≤2%
5. Essentially independent of operating temperature

Typical Characteristics

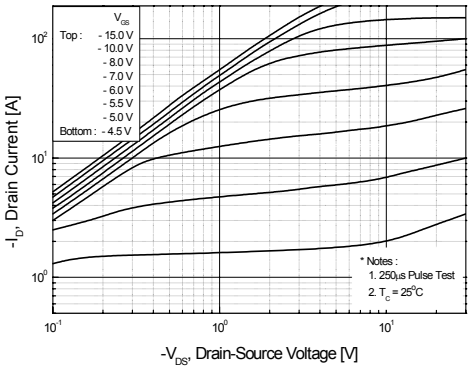


Figure 1. On-Region Characteristics

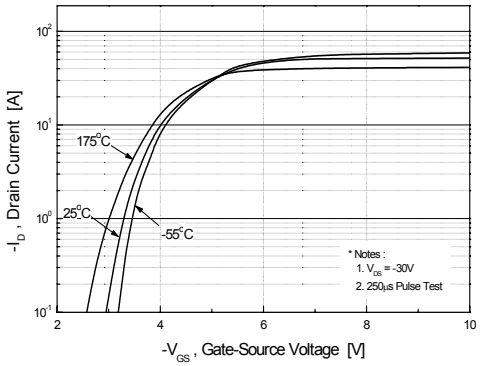


Figure 2. Transfer Characteristics

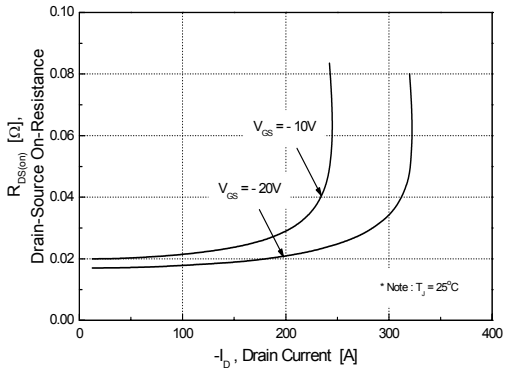


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

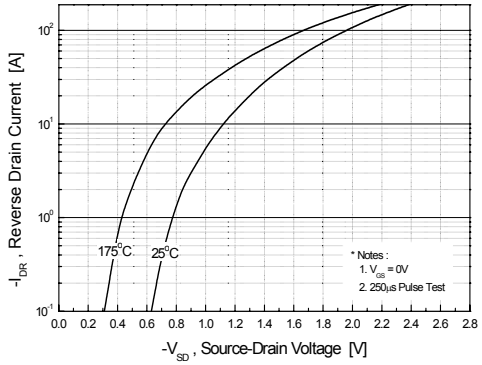


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

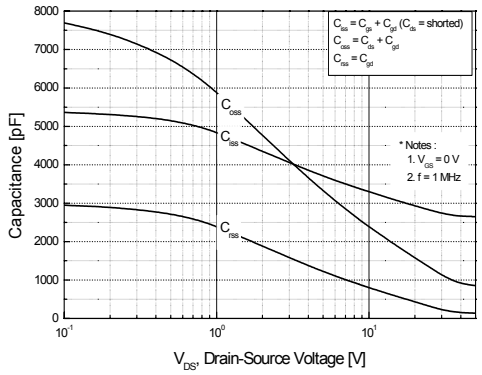


Figure 5. Capacitance Characteristics

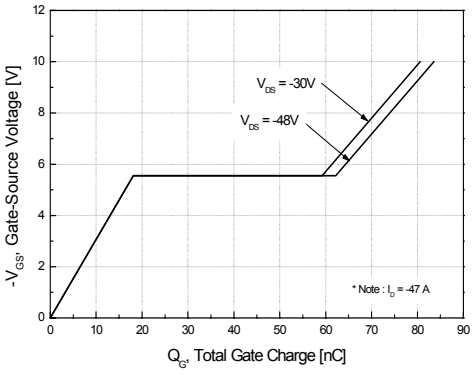


Figure 6. Gate Charge Characteristics

Typical Characteristics (Continued)

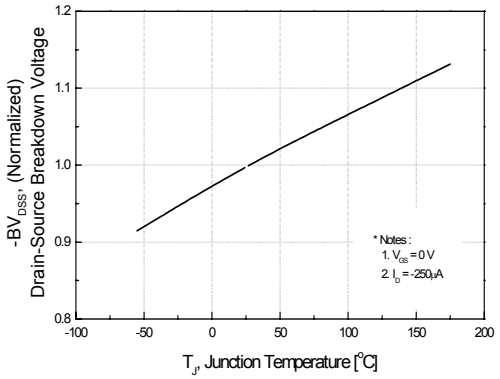


Figure 7. Breakdown Voltage Variation vs. Temperature

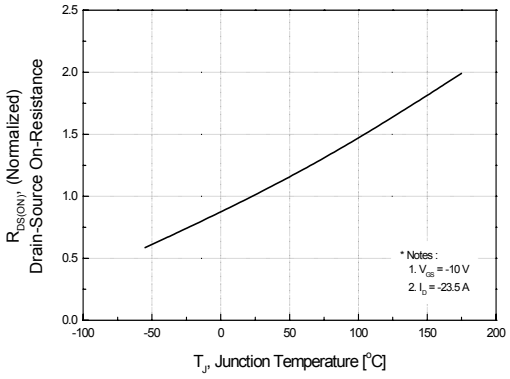


Figure 8. On-Resistance Variation vs. Temperature

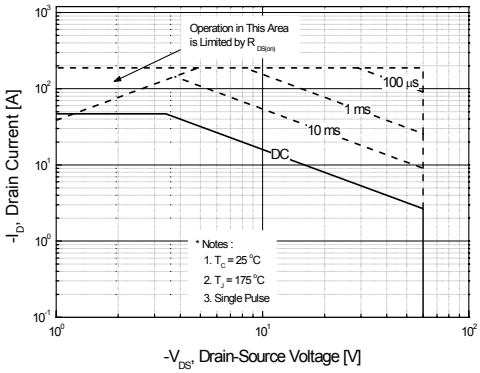


Figure 9. Maximum Safe Operating Area

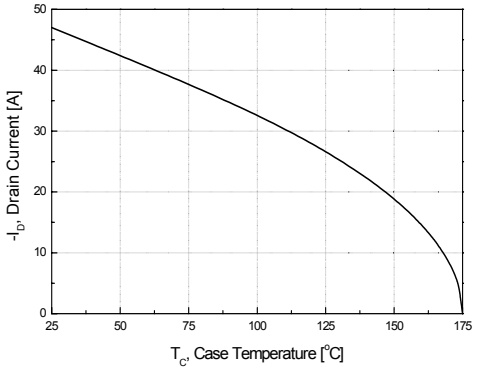


Figure 10. Maximum Drain Current vs. Case Temperature

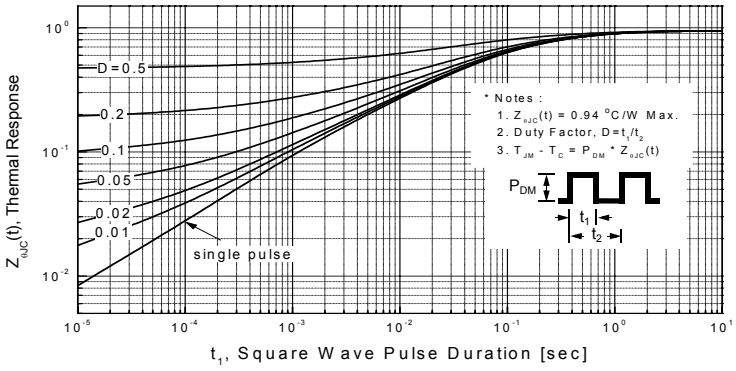
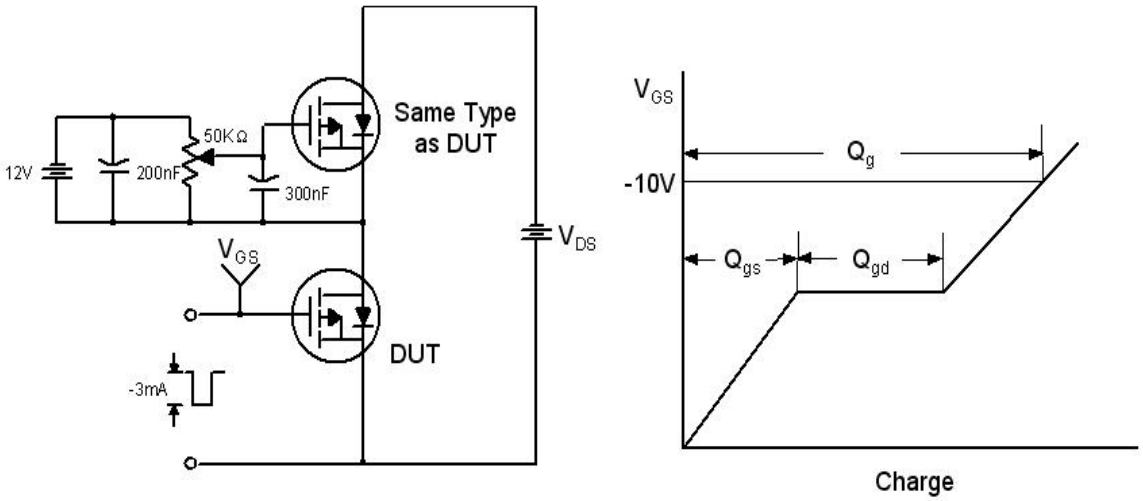
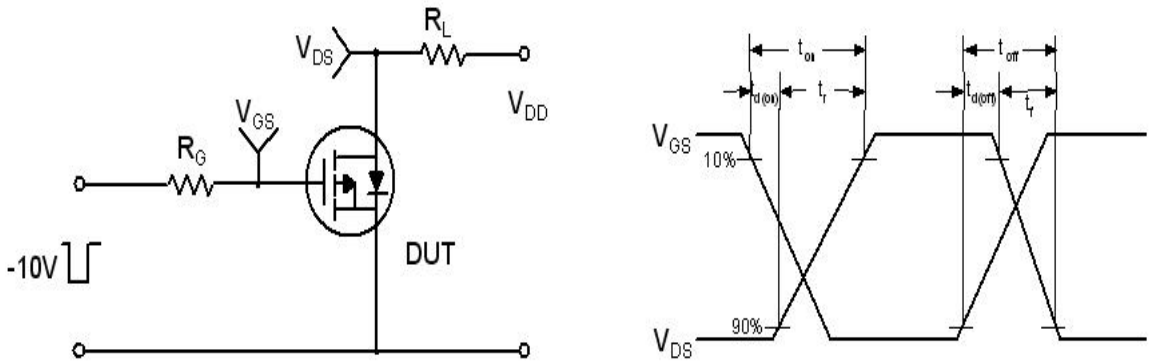


Figure 11. Transient Thermal Response Curve

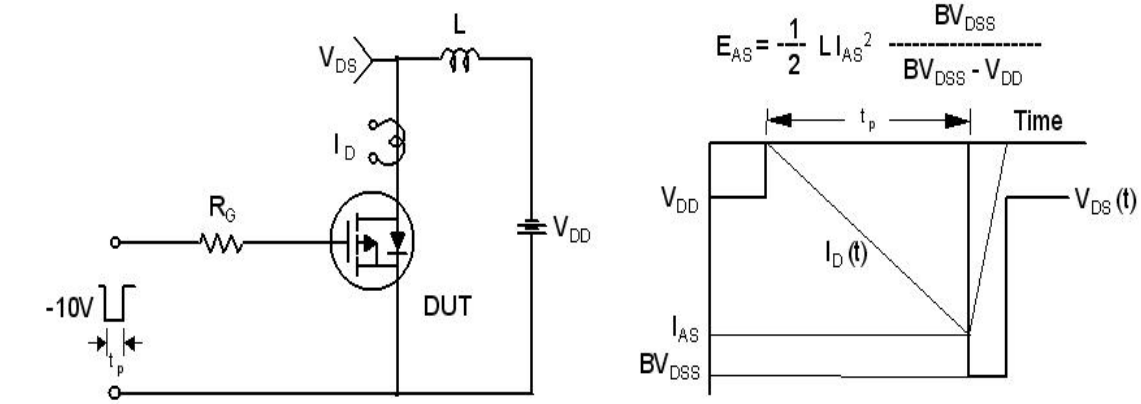
Gate Charge Test Circuit & Waveform



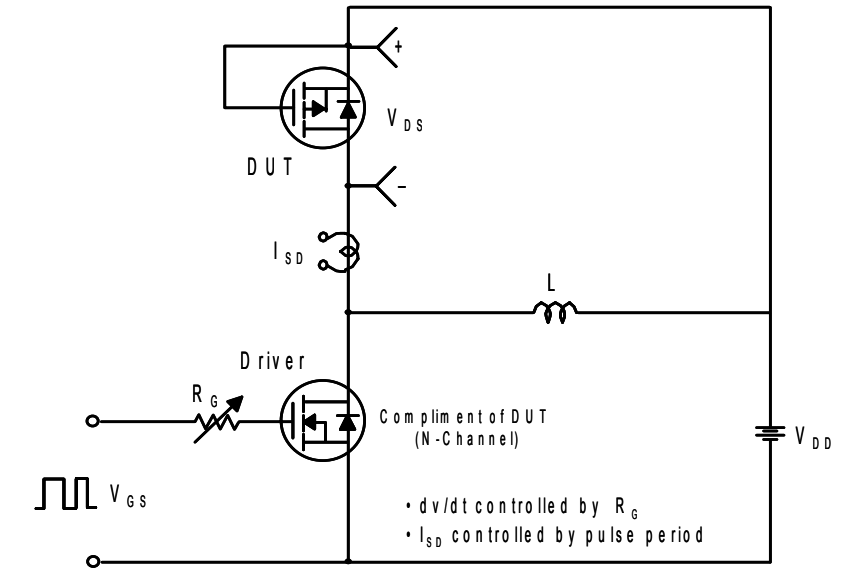
Resistive Switching Test Circuit & Waveforms

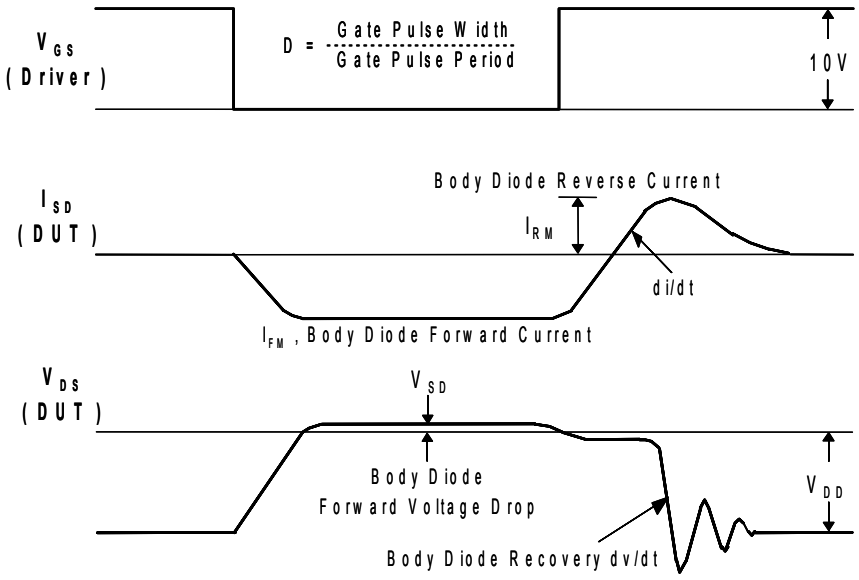


Unclamped Inductive Switching Test Circuit & Waveforms



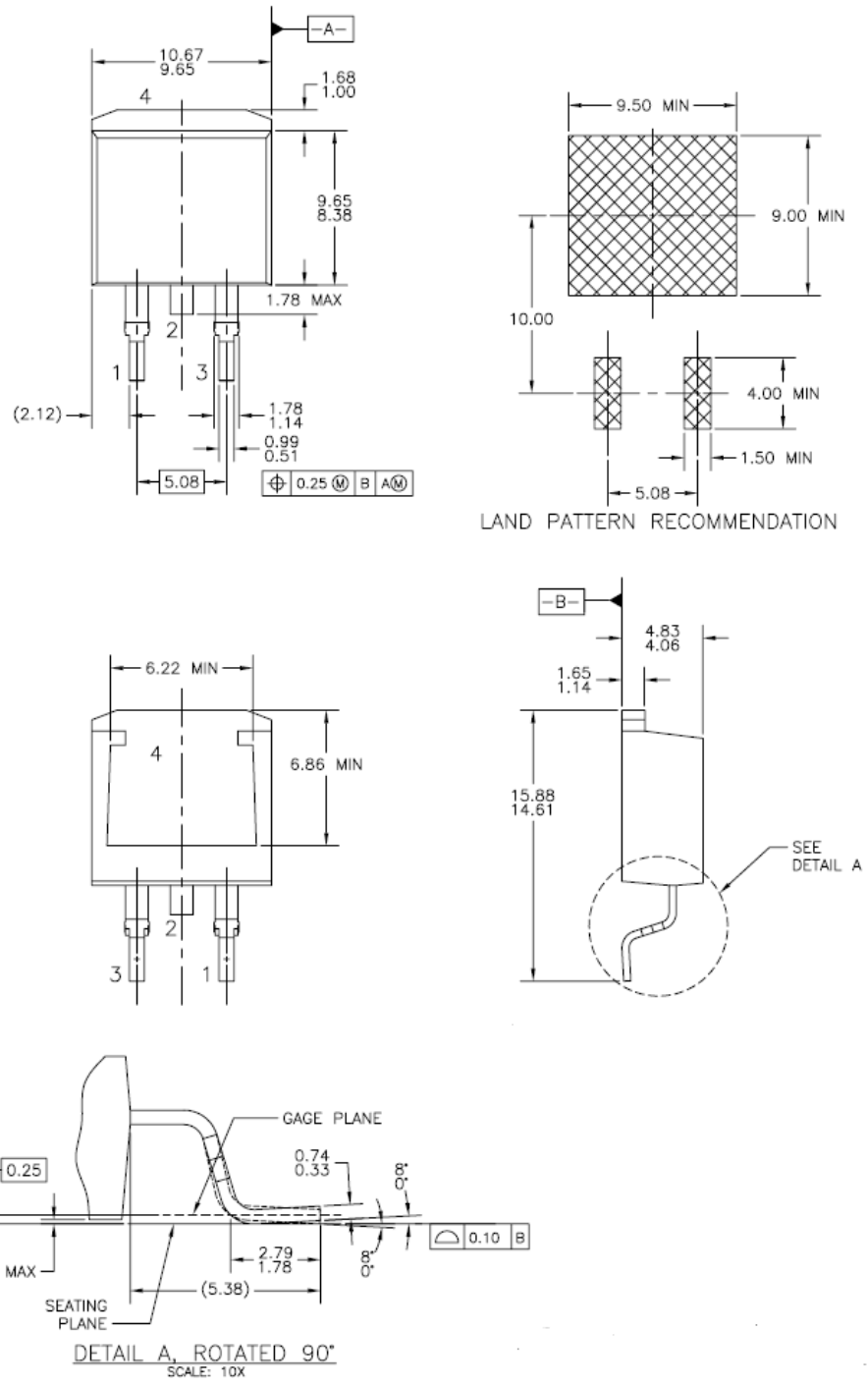
Peak Diode Recovery dv/dt Test Circuit & Waveforms





Mechanical Dimensions

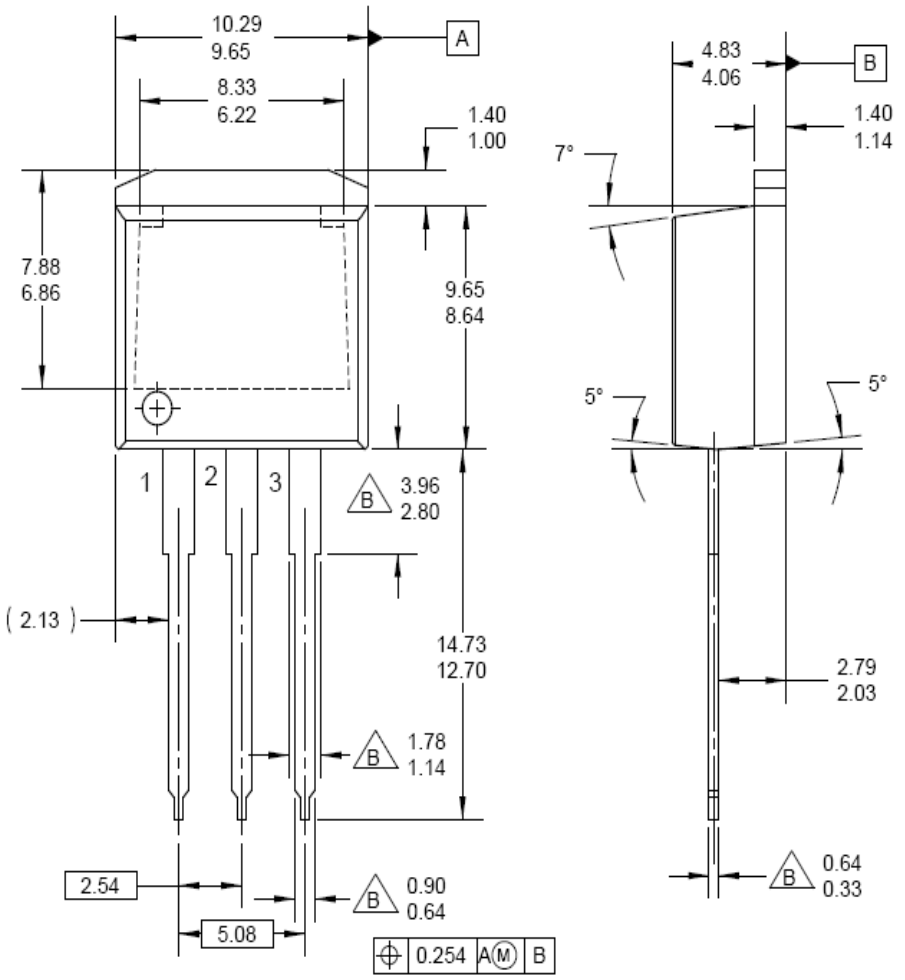
D^2 - PAK



Dimensions in Millimeters

Mechanical Dimensions

I^2 - PAK



Dimensions in Millimeters

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